

AMENDMENTS TO THE SPECIFICATION

Please replace the paragraph beginning at page 2, line 13 with the following amended paragraph:

~~FIGs. 1-8 are FIG. 1 is a cross section sections of a SOI device in sequential steps of at a stage in formation according to an a first embodiment of the invention;~~

Please add the following new paragraphs after the paragraph that replaces the paragraph at page 2, line 13 with the following:

FIG. 2 is a cross section of the SOI device of FIG. 1 at a stage in formation subsequent to that shown in FIG. 1 according to the first embodiment of the invention;

FIG. 3 is a cross section of the SOI device of FIG. 1 at a stage in formation subsequent to that shown in FIG. 2 according to the first embodiment of the invention;

FIG. 4 is a cross section of the SOI device of FIG. 1 at a stage in formation subsequent to that shown in FIG. 3 according to the first embodiment of the invention;

FIG. 5 is a cross section of the SOI device of FIG. 1 at a stage in formation subsequent to that shown in FIG. 4 according to the first embodiment of the invention;

FIG. 6 is a cross section of the SOI device of FIG. 1 at a stage in formation subsequent to that shown in FIG. 5 according to the first embodiment of the invention;

FIG. 7 is a cross section of the SOI device of FIG. 1 at a stage in formation subsequent to that shown in FIG. 6 according to the first embodiment of the invention;

FIG. 8 is a cross section of the SOI device of FIG. 1 at a stage in formation subsequent to that shown in FIG. 7 according to the first embodiment of the invention;

Please replace the paragraph beginning at page 2, line 15 with the following amended paragraph:

~~FIGs. 9-14 are FIG. 9 is a cross section sections of a SOI device in sequential steps of at a stage in formation according to an alternative a second embodiment of the invention;~~

Please add the following new paragraphs after the paragraph that replaces the paragraph at page 2, line 15 with the following:

FIG. 10 is a cross section of the SOI device of FIG. 9 at a stage in formation subsequent to that shown in FIG. 9 according to the second embodiment of the invention;

FIG. 11 is a cross section of the SOI device of FIG. 9 at a stage in formation subsequent to that shown in FIG. 10 according to the second embodiment of the invention;

FIG. 12 is a cross section of the SOI device of FIG. 9 at a stage in formation subsequent to that shown in FIG. 11 according to the second embodiment of the invention;

FIG. 13 is a cross section of the SOI device of FIG. 9 at a stage in formation subsequent to that shown in FIG. 12 according to the second embodiment of the invention;

FIG. 14 is a cross section of the SOI device of FIG. 9 at a stage in formation subsequent to that shown in FIG. 13 according to the second embodiment of the invention;